NPN Triple Diffused Planar Silicon Transistor



2SC3149

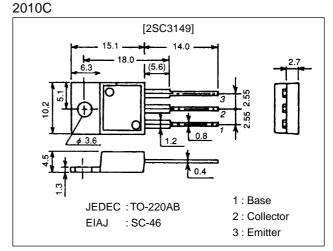
800V/1.5A Switching Regulator Applications

Features

- · High breakdown voltage ($V_{CBO} \ge 900V$).
- · Fast switching speed.
- \cdot Wide ASO.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		900	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		1.5	A
Collector Current (Pulse)	I _{CP}	PW≤300µs, Duty Cycle≤10%	5	A
Base Current	Ι _Β		0.8	A
Collector Dissipation	PC	Tc=25°C	40	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falanetei			min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =800V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			10	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =0.1A	10*		40*	
	h _{FE} 2	V _{CE} =5V, I _C =0.5A	8			
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.1A		15		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		30		pF

*: The $h_{FE}l$ of the 2SC3149 is classified as follows. When specifying the $h_{FE}l$ rank, specify two ranks or more in principle.

10 K 20 15 L 30 20 M 40

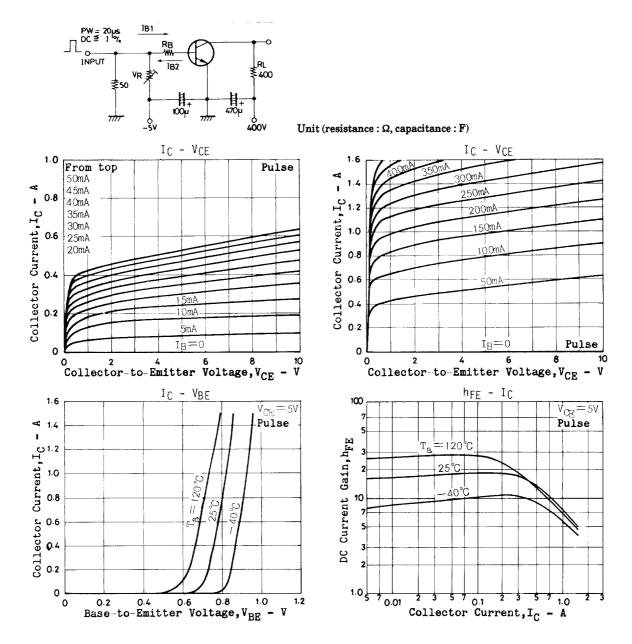
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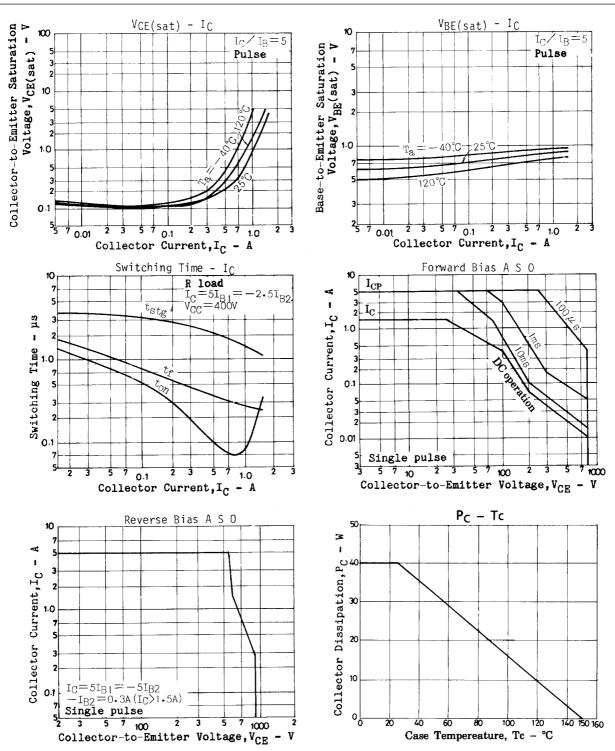
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =0.75A, I _B =0.15A			2.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =0.75A, I _B =0.15A			1.5	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =1mA, I _E =0	900			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	800			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEO(sus)}	I _C =1.5A, L=1mH, I _B =0.5A	800			V
Collector-to-Emitter Sustain Voltage	VCEX(sus)1	I _C =0.5A, I _{B1} =0.1A, I _{B2} =-0.1A, L=5mH, clamped	800			V
	VCEX(sus)2	I _C =0.25A, I _{B1} =0.05A, I _{B2} =–0.05A, L=10mH, clamped	900			V
Turn-ON Time	ton	I_{C} =1A, I_{B1} =0.2A, I_{B2} =-0.4A, R_{L} =400 Ω , V_{CC} =400V			1.0	μs
Storage Time	t _{stg}	I_{C} =1A, I_{B1} =0.2A, I_{B2} =-0.4A, R_{L} =400 Ω , V_{CC} =400V			3.0	μs
Fall Time	t _f	I_{C} =1A, I_{B1} =0.2A, I_{B2} =-0.4A, R_{L} =400 Ω , V_{CC} =400V			0.7	μs

Switching Time Test Circuit





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